



## DN0150ALP4 / DN0150BLP4

#### 50V NPN SMALL SIGNAL TRANSISTOR IN DFN1006

#### Features

- BV<sub>CEO</sub> > 50V
- I<sub>C</sub> = 100mA High Collector Current
- P<sub>D</sub> = 1000mW Power Dissipation
- 0.60mm<sup>2</sup> Package Footprint, 13 times Smaller than SOT23
- 0.4mm Height Package Minimizing Off-Board Profile
- Complementary PNP Type: DP0150ALP4/DP0150BLP4
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

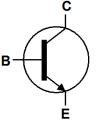
## **Mechanical Data**

- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
  Terminals: Finish NiPdAu.
- Solderable per MIL-STD-202, Method 208@
- Weight: 0.0008 grams (Approximate)

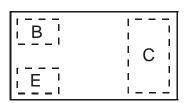


X2-DFN1006-3

**Bottom View** 



**Device Symbol** 



Top View Pin Configuration

## Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
DN0150ALP4-7	Т3	7	8	3,000
DN0150ALP4-7B	Т3	7	8	10,000
DN0150BLP4-7	T4	7	8	3,000
DN0150BLP4-7B	T4	7	8	10,000

Notes: 1 No purp

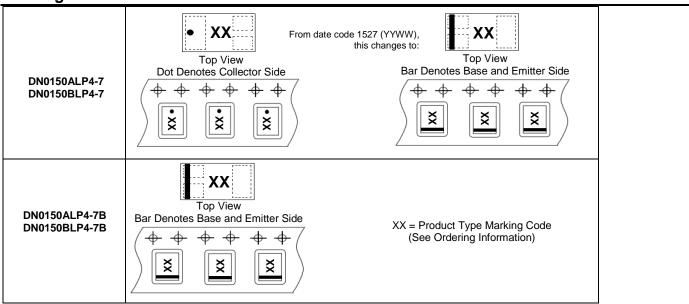
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

 See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

For packaging details, go to our website at http://www.diodes.com/products/packages.html.

#### **Marking Information**





# Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	50	V
Emitter-Base Voltage	V <sub>EBO</sub>	5	V
Collector Current – Continuous	Ic	100	mA
Peak Pulse Collector Current	ICM	200	mA
Base Current	Ι <sub>Β</sub>	30	mA

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit			
Power Dissipation	(Note 5)	D-	400	mW		
	(Note 6)	P <sub>D</sub>	1000	111VV		
Thermal Desistance, Junction to Ambient	(Note 5)		310	°C/W		
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>θJA</sub>	120	-0/00		
Thermal Resistance, Junction to Lead (Note 7)		R <sub>θJL</sub>	120	°C/W		
Operating and Storage and Temperature Ran	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C			

#### ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

### Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS	OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage		<b>BV</b> CBO	60	-	_	V	$I_{C} = 10 \mu A, I_{E} = 0$
Collector-Emitter Breakdown Voltage	e (Note 8)	BV <sub>CEO</sub>	50	—	_	V	$I_{\rm C} = 1 {\rm mA}, I_{\rm B} = 0$
Emitter-Base Breakdown Voltage		BVEBO	5	_		V	$I_{E} = 10 \mu A, I_{C} = 0$
Collector Cut-Off Current		I <sub>CBO</sub>		_	0.1	μA	$V_{CB} = 60V, I_E = 0$
Emitter Cut-Off Current		I <sub>EBO</sub>	_	—	0.1	μA	$V_{EB} = 5V, I_{C} = 0$
ON CHARACTERISTICS (Note 9)							
Collector-Emitter Saturation Voltage		V <sub>CE(SAT)</sub>		0.10	0.25	V	I <sub>C</sub> = 100mA, I <sub>B</sub> = 10mA
DC Current Gain	DN0150ALP4		120	—	240		$V_{CE} = 6V, I_C = 2mA$
	DN0150BLP4	h <sub>FE</sub>	200	—	400		
SMALL SIGNAL CHARACTERISTICS							
Transition Frequency		f <sub>T</sub>	60	—	—	MHz	$V_{CE} = 10V$ , $I_E = -1mA$ f = 30MHz
Output Capacitance		C <sub>ob</sub>		1.3	_	pF	$V_{CB} = 10V, I_E = 0,$ f = 1MHz

Notes: 5. For the device mounted on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady state condition. The entire exposed collector pad is attached to the heatsink.

6. Same as Note 5, except the exposed collector pad is mounted on 25mm x 25mm 2oz copper.

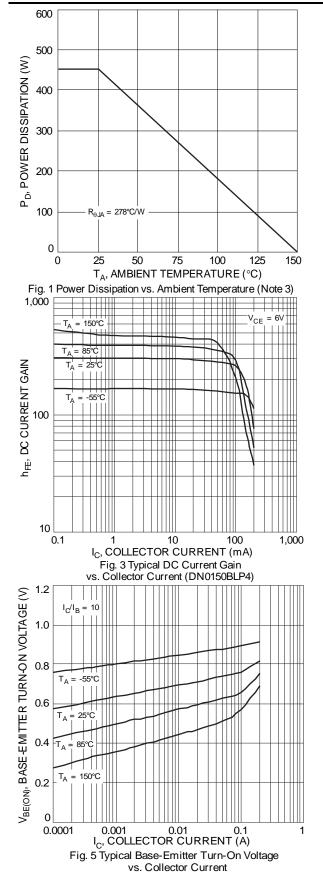
7. Thermal resistance from junction to solder-point (on the exposed collector pad).

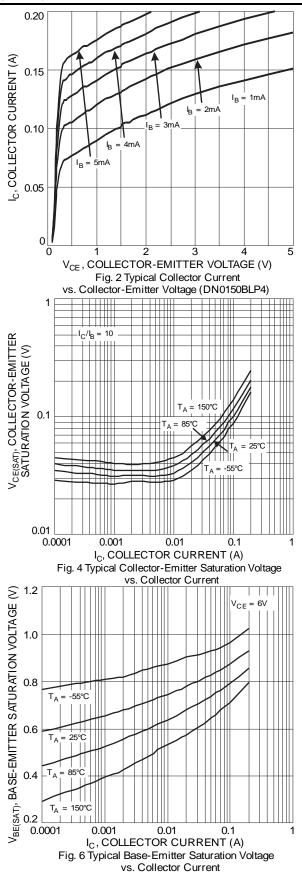
8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

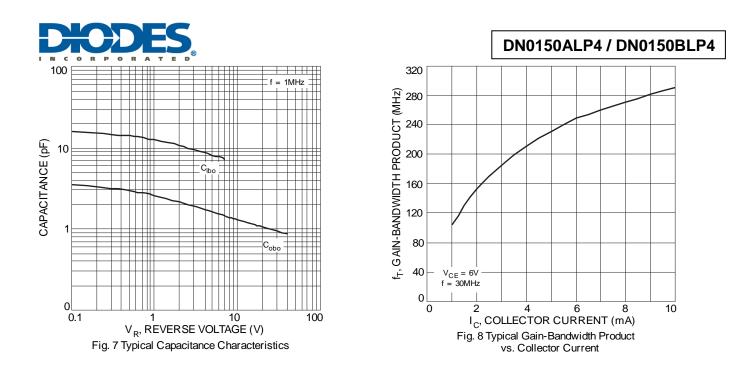
9. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu s.$  Duty cycle  $\leq$  2%.



## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

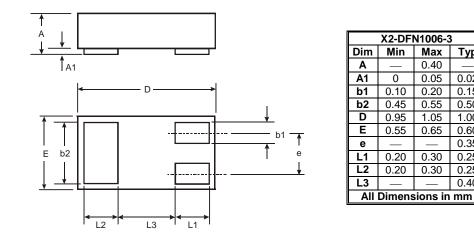






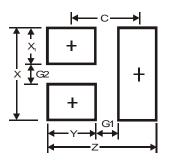
## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



## Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	1.1
G1	0.3
G2	0.2
Х	0.7
X1	0.25
Y	0.4
C	0.7

Тур

0.02

0.15

0.50

1.00

0.60

0.35

0.25

0.25

0.40



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